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/RX	~ \ \	SURE STATEMENT	Docket No.						
MA	( 1 5 2003 🛠 )	(c))	AM-3245						
In Right	pplication f: I	Hoiman (Raymond) HUNG et al.		N					
	Serial No.	Filing Date	Examiner	Group Art Unit					
09/276,376		March 25, 1999	A. Olsen	1763					
Title:	ENHANCEMENT	F OF SILICON OXIDE ETCH RA	TE AND NITRIDE SELECTIVITY	,					
USING	G HEXAFLUORO	BUTADIENE OR OTHER HEAV	Y PERFLUOROCARBON						
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	<del></del>		dress to:	<del></del>					
			missioner for Patents ton, D.C. 20231	# 23 5120153 mw					
		<b>3</b> -	,	5120103					
		37 CI	FR 1.97(b)	mω					
1.	The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.								
	e123	37 CF	FR 1.97(c)						
2. 🔀	The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:								
	★ the statem	nent specified in 37 CFR 1.97(e);							
		OR	RE	CEIVED					
	☐ the fee se	t forth in 37 CFR 1.17(p).	MΔ	Y 16 2003					
				C 1700					

## OF INFORMATION DISCLOSURE STATEMENT Docket No. (Under 37 CFR 1.97(b) or 1.97(c)) MAY 1 5 2003 AM-3245 e Applic Hoiman (Raymond) HUNG et al. Serial No. Filing Date Examiner Group Art Unit 09/276,376 March 25, 1999 A. Olsen 1763 ENHANCEMENT OF SILICON OXIDE ETCH RATE AND NITRIDE SELECTIVITY USING HEXAFLUOROBUTADIENE OR OTHER HEAVY PERFLUOROCARBON Payment of Fee (Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p)) A check in the amount of is attached. ☑ The Assistant Commissioner is hereby authorized to charge and credit Deposit Account No. 50-0636 as described below. A duplicate copy of this sheet is enclosed. Charge the amount of X Credit any overpayment. Charge any additional fee required. Certificate of Transmission by Facsimile\* Certificate of Mailing by First Class Mail I certify that this document and authorization to charge deposit I certify that this document and fee is being deposited account is being facsimile transmitted to the United States on May 13, 2003 with the U.S. Postal Service Patent and Trademark Office (F as first class mail under 37 C.F.R. 1.8 and is addressed to the Assistant Commissioner for Patents, Washington, D.C. 20231. (Date) Signature Signature of Person Mailing Correspondence Ingrid C. Mallory Typed or Printed Name of Person Signing Certificate Typed or Printed Name of Person Mailing Certificate \*This certificate may only be used if paying by deposit account. Dated: May 13, 2003 Signature Charles S. Guenzer, Reg. No. 30,640 (650) 566-8040 Mailing Address: Applied Materials, Inc. Patent/Legal Department P.O. Box 450A Santa Clara, CA 95052

CC:

## STATEMENT UNDER 37 CFR 1.97(e) ACCOMPANYING INFORMATION DISCLOSURE STATEMENT

Docket No. AM-3245

In Re Application Of: Hoiman (Raymond) HUNG et al.

Serial No.

Filing Date

Examiner

Group Art Unit

09/276,376

March 25, 1999

A. Olsen

1763

Invention: ENHANCEMENT OF SILICON OXIDE ETCH RATE AND NITRIDE SELECTIVITY

USING HEXAFLUOROBUTADIENE OR OTHER HEAVY PERFLUOROCARBON



## TO THE ASSISTANT COMMISSIONER FOR PATENTS:

This is a statement under the provisions of 37 CFR 1.97(e) in the above-identified application ECEIVED

Check applicable statement herebelow:

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Statement Under 37 CFR 1.97(e)(1)

TC 1700

Each item of information contained in the accompanying Information Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the Information Disclosure Statement.

## Statement Under 37 CFR 1.97(e)(2)

☐ No item of information contained in the accompanying Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the undersigned person, after making reasonable inquiry, no item of information contained in the accompanying Information Disclosure Statement was known to any individual designated in 37 CFR 1.56(c) more than three months prior to the filing of the Information Disclosure Statement.

Dated:

May 13, 2003

Charles S. Guenzer, Reg. No. 30,640

(650) 566-8040

Mailing Address:

Applied Materials, Inc.

Patent/Legal Department

P.O. Box 450A

Santa Clara, CA 95052

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May 13, 2003

with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the

Assistant Commissioner for Patents, Washington, D.C.

20231.

Ingrid C. Mallory

Typed or Printed Name of Person Mailing Correspondence

CC:

3600.3245



U.S. Departm	nent of Co	mmerce, Patent ar	Docket 1	Docket No. AM-3245					
OLPA						Serial No.: <b>09/276,376</b>			
LIST OF RELEVANT ART CITED BY APPLICANT						Applicant: Hoiman (Raymond) Hung et a			
MAY 1 5 2003 (Use several sheets if necessary)						Filing Date: March 25, 1999			
The second secon						Group: 1763			
HADEN			Ţ	J.S. PATENT DOCUMEN	TS				
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	AC	6,365,060	04/02/02	Nagaseki et al.	216	59			
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	AO	10-313009	11/24/98	JP			Abstract		
	AP	6-275568	09/30/94	JР			Abstract		
			FR ART (Incl	uding Author, Title, Date, I	Pertinent Pages	, Etc.)			
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